Supporting Information

Stepwise Electrochemical Reconstruction of Bi-Based Anode for Enhanced Aqueous Battery Energy Storage

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Supplementary Equation:

$$D = R^2 T^2 / 2A^2 n^4 F^4 C^2 R \sigma^2 \tag{1}$$

$$Z' = Rs + Rct + \sigma \omega^{-1/2}$$
(2)

Where **R** (J mol⁻¹ K⁻¹), **T** (K), **A** (cm⁻²), **n**, **F** (C mol⁻¹), **C** (L mol⁻¹), **\sigma** and **\omega** (Hz) are the gas constant, absolute temperature, reaction area of electrode, quantity of transferred electrons, Faraday constant, concentration of electrolyte, Warburg diffusion coefficient, and angular frequency, respectively.

Supplementary Figures:



Figure S1. SEM images of α -Bi₂O₃.



Figure S2. CV curves obtained at varying numbers of electrochemical reconstruction cycles.



Figure S3. SEM image of electrochemically restructured in the fifth cycle.



Figure S4. SEM image of $BiO_x@BiO/Bi$ electrochemically restructured in the tenth cycle.



Figure S5. SEM image of $BiO_x@BiO/Bi$ electrochemically restructured in the fifteenth cycle.



Figure S6. SEM image of the CV activation without α -Bi₂O₃ electrolyte.



Figure S7. EPR spectra of without adding α -Bi₂O₃ after CV activation.



Figure S8. CV and GCD curves of α -Bi₂O₃ electrode.



Figure S9. GCD curves of α -Bi₂O₃ and BiO_x@BiO/Bi electrode.



Figure S10. TEM image of $BiO_x@BiO/Bi$ in the charged state.



Figure S11. TEM images of BiO_x@BiO/Bi in the discharged state.



Figure S12. SEM images of $BiO_x@BiO/Bi$ at the discharged state, half-discharged state and charged state after 1000 cycles.



Figure S13. Stress simulation diagram of $BiO_x@BiO/Bi$ (red represents tensile stress, blue represents compressive stress).



Figure S14. $BiO_x@BiO/Bi$ electrode of the relationship between peak currents and scan rates.



Figure S15. CV curves of the contribution rates of the capacitance and diffusioncontrolled capacitance at different scanning rates for BiO_x@BiO/Bi.



Figure S16. Bi concentration of different sample after 2000 cycles.



Figure S17. The CV curves of the NiCo-LDH and BiO_x@BiO/Bi electrodes examined at scan rate of 5 mV s⁻¹.



Figure S18. (a) The CV and (b) GCD curves of NiCo-LDH.

Sample	$S_{BET}[m^2 g^{-1}]$	V _{pore} [cm ³ g ⁻¹]	D _{aver} [nm]
α -Bi ₂ O ₃	1.9207	0.010176	21.192
BiO _x @BiO/Bi	12.906	0.089317	27.681

Table 1. The specific surface area and pore structure of α -Bi₂O₃ and BiO_x@BiO/Bi.

S_{BET}: BET surface area

V_{pore}: Total pore volume

D_{aver}: Average pore size

Table 2. The cycle durability of $BiO_x@BiO/Bi$ electrode comparison with the latest

Electrode	Current Density	Cycle Numble	Capacity Retention	Reference
Ві	0.52 A g ⁻¹	1700	88.8%	1
Bi ₂ O ₃ rods/RGO	2 A g ⁻¹	1000	94%	2
Bi ₂ O ₂ CO ₃ /RGO-100	5 A g ⁻¹	1000	84.5%	3
Bi-Bi ₂ O ₃ /CNT	1 A g ⁻¹	1000	72.9%	4
Bi ₂ Se ₃ @C	2 A g ⁻¹	1500	82.9%	5
Bi ₂ O ₃ /porous-RGO	0.5 A g ⁻¹	3000	81.1%	6
Bi ₂ O ₃ /rGO	5 A g ⁻¹	1000	30%	7
Bi/CN _x	1 A g ⁻¹	1000	79%	8
BiO _x @BiO/Bi	2 A g ⁻¹ 5 A g ⁻¹	7000 3000	103.4% 101.7%	This Work

reported bismuth-based anodes.

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